



BCR 112F E6327 Information



For Reference Only

Part Number BCR 112F E6327 **Manufacturer** Infineon Technologies

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

Description TRANS PREBIAS NPN 250MW TSFP-3

Package SOT-723

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BCR 112F E6327 Specifications

	Report errors?
Supplier Device Package	PG-TSFP-3
Package / Case	SOT-723
Mounting Type	Surface Mount
Power - Max	250mW
Frequency - Transition	140MHz
Current - Collector Cutoff (Max)	100nA (ICBO)
Vce Saturation (Max) @ Ib, Ic	300mV @ 500μA, 10mA
DC Current Gain (hFE) (Min) @ Ic, Vce	20 @ 5mA, 5V
Resistor - Emitter Base (R2) (Ohms)	4.7k
Resistor - Base (R1) (Ohms)	4.7k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	NPN - Pre-Biased
Series	-
Package	SOT-723
	Transistors - Bipolar (BJT) - Single, Pre-Biased
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Manufacturer	Infineon Technologies
Manufacturer Part Number	BCR 112F E6327

BCR 112F E6327 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BCR 112F E6327 Payment Methods



















BCR 112F E6327 Shipping Methods













If you have any question about BCR 112F E6327, please do not hesitate to contact us!

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